Michal Frivaldsky - Jan Morgos*

DC-DC CONVERTER DESIGN ISSUES FOR HIGH-EFFICIENT DC MICROGRID

In this article, the electrical properties, as well as the economic aspects of the modular and non-modular solution of the DC-DC photovoltaic converter for DC microgrid subsystem, are described. Principally a theoretical overview of the circuit configuration for the selected DC-DC stage of the DC microgrid system is shown. It is dealt with the comparison of the one non-modular high-voltage SiC-based dual-interleaved converter operating at the low switching frequency and with modular low-voltage GaN-based DC-DC converters operating at high switching frequencies. The main focus is given to the research of the dependency that arises from the different module count, overall efficiency, costs, and power density (system volume). High efficiency, reduced overall volume, and maximum power density are important factors within modern and progressive solar systems. It is assumed that with the increase of switching frequency within the modular system the volume reduction of the passive components will be highly demanded, thus PCB dimensions and overall volume can be reduced. This dependency is investigated, while the total volume of the non-modular system is a unit of the measure. For these purposes, the design of variant solution was done, and consequently mutually compared in the way of simulations and experimental measurements.

Keywords: modular system, efficiency, cost, GaN, SiC

1. Introduction

Humankind has come to a stage where it is evident that the climatic changes of our planet are so extensive that our way of life cannot be sustained for a long time. The measures to reduce the impact on the climate changes also include a change of the process of the use of primary energy source - fossil fuels. Nowadays, many attempts have been done in order to shift from fossil fuels to clean or renewable primary energy sources (photovoltaic systems, wind and water turbines, energy hubs and smart-grids) [1-4].

Strong development of the green and alternative or renewable energy systems (RES) has been intensively investigated for almost a decade. In most of the European countries, it has occurred since 2008, when the European Union’s effort to introduce mandatory RES shares in the energy sector for all EU Member States culminated [5].

The electricity system and the overall energy sector are currently under the influence of significant changes. On the one hand, there is increasing pressure on new, mostly small, electricity sources. Whether it is the use of solar energy or biomass (biogas, the conversion of bio-waste to energy, etc.), but also other technologies. At the same time, however, there is a gradual change in consumer models. Global requirements on the energy consumption continuously grow. One of the ways how to provide smooth and reliable energy distribution lies also in the utilization of the very highly efficient systems with considerable power densities [6, 7].

From this point of view, it is therefore important to develop hardware and software solutions that would provide optimal energy management between the supply grid and consumer (household) and also between individual components of the energy system of modern household (primary sources of energy, accumulation of energy, and energy distribution to the consumers). Moreover, if such an intelligent power hub could co-operate with other nodes in its vicinity (narrower or wider), the technical conditions would be created for the massive use of electric cars and renewable sources without negative impact on the power distribution grid [8, 9].

In this paper, a proposal for the intelligent power hub is given, while the more detailed focus is given on the construction block of the power converter system. It deals with DC-DC photovoltaic converter, which can be designed in several ways [10]. In this paper, the modular and non-modular solution of the buck-boost bi-directional converter is considered, while the focus is given on the mutual comparison of the efficiency, cost, and power density for the target application.

2. The concept of an energy hub for DC microgrid

Due to increased use of the portion of solar energy and other renewable energy sources, it is necessary to consider with intelligent energy hubs within DC-microgrids of the households. There is also the visible rise of the use of electric vehicles that also influences the concept of smart energy hubs. Such hub has to optimally manage energy flow between individual energy storage systems and energy sources/consumers. Also, there is a need to gain information about energy consumption and state of the charge of energy storage systems. There is the possibility of an Internet connection and possibility to control and monitor system from anywhere with the use of IoT systems.

- A principal block diagram of the concept of perspective energy hub is shown in Figure 1. The system consists of photovoltaic cells,
the input voltage is divided between the serial connection of the modular converter blocks. The output voltage for both concepts shall be 600 V, thus for the non-modular solution the output is single, while the modular solution is defined again by the serial connection of the outputs of the individual converters in order to generate an output voltage of 600 V.

Main circuit topology of the non-modular solution is based on the non-isolated DC-DC interleaved synchronous boost converter with SiC-based transistors and diodes. A circuit schematic of this converter is shown in Figure 3. Due to interleaved topology, it is possible to achieve low current and voltage stress for the semiconductor components, and lower voltage and current ripple at the output filtering capacitor. Another benefit is also reduction of the volume of boost inductor and improved thermal performance of the total system.

Individual building blocks of the modular system, shown on Figure 4, are based on the GaN technology of the semiconductor components. Due to dividing the power and voltages to separate individual blocks, it is possible to increase switching frequency several times. One DC-DC converter thus operates with lower voltage and power (thus low voltage - high current, high frequency switching devices can be used). Such approach might reduce dimensions of used components (magnetic components, capacitors, PCB). Thanks to lower dimensions it is possible to design converters with smaller PCB, while the volume of a complex modular system would be smaller compared to the non-modular system.

### Table 1: Table of input parameters for the proposed system

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Output voltage range from PV panels</td>
<td>500 - 560 V DC</td>
</tr>
<tr>
<td>Output power from PV panels</td>
<td>10 kW peak</td>
</tr>
<tr>
<td>Output voltage (DC bus voltage)</td>
<td>600 V DC</td>
</tr>
<tr>
<td>Output MPPT converter power</td>
<td>10 kW peak</td>
</tr>
</tbody>
</table>

In this paper, the attention is given to the MPPT DC-DC converter block, while topological optimization is realized in the way of achieving the highest possible efficiency, lowest possible costs and dimensions for defined input-output conditions. Comparison of the modular and non-modular concept is described.

### 3. The non-modular and modular concept of DC-DC MPPT converter

In this part topological analysis of MPPT DC-DC converter is given. Since the design of MPPT converter has to be adjusted to the target application (exact number of cells/modules) the input/output parameters are exactly defined, and the proposed solutions are designed considering required voltages and currents (Table 1).

Principal block diagrams for non-modular and modular solutions are shown in Figure 2. Input voltage for the non-modular system is directly connected to the input of the converter at full level (serially connected PV strings). For the modular system, the input voltage is divided between the serial connection of the modular converter blocks. The output voltage for both concepts shall be 600 V, thus for the non-modular solution the output is single, while the modular solution is defined again by the serial connection of the outputs of the individual converters in order to generate an output voltage of 600 V.

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Next Equations (1) - (3) have been used for the determination of the main circuit components that are affecting the converter volume. The input and output variables have been modified, i.e. input/output voltage and duty cycle, when modular and the non-modular concept was considered. The percentage of the ripple of the output variables was the same even the numbers of the modules vary.

\[
L[H] = \frac{U_{in} * (V_{out} - V_{in})}{f_{sw} * \Delta i_{L} * \frac{V_{out}}{V_{in}}},
\]

where:
\( U_{in} \) - input converter voltage [V],
\( U_{out} \) - output converter voltage [V],
\( f_{sw} \) - switching frequency [Hz],
\( \Delta i_{L} \) - ripple of inductor current [%],
\( I_{out,max} \) - maximum output current [A].

\[
D(\%) = 1 - \frac{V_{in,min}}{V_{out}}.
\]

where:
\( U_{in} \) - minimum input converter voltage [V],
\( U_{out} \) - output converter voltage [V].

\[
C_{out}[F] = \frac{I_{out, max} * D}{f_{sw} * \Delta U_{out} * \frac{V_{out}}{V_{in}}},
\]

where:
\( I_{out, max} \) - maximum output current [A],
\( D \) - duty cycle [%].
3. Comparison of the properties of the modular and non-modular solution - costs, efficiency, volume, performance

At this place, the economic performance together with efficiency and power density calculation are given. Initially, Table 3 shows an expert estimation of the investments necessary for the design of proposed solutions of the MPPT DC-DC converter. The estimation considers with the whole bill of materials of electronic parts (power semiconductor components, drivers, magnetic components, passive components and PCB), while standard distribution network was considered. It is seen, that the initial costs of the non-modular DC-DC interleaved converter based on the SiC technology is comparable to the initial costs that are relevant for almost up to 16-stage modular DC-DC converter. Figure 7 shows graphical interpretation of the costs related in dependency on the number of modules, while switching frequency is also variable. From Figure 7 can be seen, that with the increase of the switching frequency the costs are decreasing, what is related to the fact, that smaller reactive components can be used within...
and input/output parameters that are limited due to power delivery and semiconductor performance. For high power levels, it is expected to operate at lower frequencies in order to prevent from unwanted negative impacts (safety reasons, EMC etc.), while robust semiconductors must be used (IGBT, SiC MOSFETS).

On the other hand, modular solution enables to split individual the converter’s main circuit. Also, the drop of the cost is visible around the 8 count of the modules. It is caused due to fact, that the transistor with lower drain-source voltage can be used within main circuit, thus the price for the semiconductor reduces.

Considering volume (power density), non-modular solution exhibits performance that is dependent on the switching frequency and input/output parameters that are limited due to power delivery and semiconductor performance. For high power levels, it is expected to operate at lower frequencies in order to prevent from unwanted negative impacts (safety reasons, EMC etc.), while robust semiconductors must be used (IGBT, SiC MOSFETS). On the other hand, modular solution enables to split individual

<table>
<thead>
<tr>
<th>Table 3 Table of build costs of the proposed system</th>
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</thead>
<tbody>
<tr>
<td>T</td>
</tr>
<tr>
<td>-----</td>
</tr>
<tr>
<td>non modular (50 kHz)</td>
</tr>
<tr>
<td>2 modules (100 kHz)</td>
</tr>
<tr>
<td>4 modules (100 kHz)</td>
</tr>
<tr>
<td>8 modules (100 kHz)</td>
</tr>
<tr>
<td>16 modules (100 kHz)</td>
</tr>
<tr>
<td>20 modules (100 kHz)</td>
</tr>
</tbody>
</table>

Figure 7 Comparison of costs of non-modular and modular solution in dependency on switching frequency and number of modules

Figure 8 Comparison of build volumes of modular solutions for different switching frequencies and for different module count
The efficiency of modular system can be calculated as:

\[ \eta = \frac{n \times P_{\text{out}}}{n \times P_{\text{in}}} = \frac{P_{\text{out}}}{P_{\text{in}}} \]  \hspace{1cm} (4)

where:
- \( n \) - module count,
- \( \eta \) – efficiency,
- \( P_{\text{in}} \) - input power,
- \( P_{\text{out}} \) - output power.

From Figure 9 is seen that the main disadvantage of the increase of module count is efficiency decrease. Therefore optimizations within main circuit must be done in order to reduce the most of conduction losses (due to higher currents). For this reason there shall be compromise between previously mentioned abilities (power density and costs) and target efficiency. Almost 8 module systems are able to operate at relatively very high efficiency 95% and high switching frequency (500 kHz). In this way the volume can be decreased compared to non-modular solution (Figure 8) while investments can be reduced by more than 40% of non-modular costs.

Graphical comparison of overall efficiency of the modular solution in dependency on module count and switching frequency is shown in Figure 9. Individual results have been received from the PSpice simulations, while high-precision models of semiconductors and passive components have been utilized. Non-modular solution was evaluated for the 75 kHz, whereby the efficiency was 98.5% and is not plotted. For the calculation of efficiency of modular solution, Equations (4) and (5) were used. It is obvious that with the increasing module count, there is a decrease of overall efficiency of the modular solution. Also the increase of switching frequency causes the decrease of overall efficiency due to increase of switching and conduction losses.

<table>
<thead>
<tr>
<th>Module count</th>
<th>Input voltage ripple</th>
<th>Input current ripple</th>
<th>Output voltage ripple</th>
<th>Output current ripple</th>
</tr>
</thead>
<tbody>
<tr>
<td>1 (SiC)</td>
<td>0.04%</td>
<td>36.5%</td>
<td>3.96%</td>
<td>3.88%</td>
</tr>
<tr>
<td>2 (GaN)</td>
<td>0.02%</td>
<td>5.31%</td>
<td>0.33%</td>
<td>0.35%</td>
</tr>
<tr>
<td>4 (GaN)</td>
<td>0.03%</td>
<td>5.63%</td>
<td>0.21%</td>
<td>0.22%</td>
</tr>
<tr>
<td>8 (GaN)</td>
<td>0.08%</td>
<td>6.37%</td>
<td>0.21%</td>
<td>0.21%</td>
</tr>
</tbody>
</table>

The efficiency of modular system can be calculated as:

\[ \eta = \frac{n \times P_{\text{out}}}{n \times P_{\text{in}}} = \frac{P_{\text{out}}}{P_{\text{in}}} \]  \hspace{1cm} (5)

Final comparison of presented design approaches was realized through investigation of the input/output current/voltage ripple. From Table 4 is seen, that visible reduction can be achieved with modular solution thus improving the distortion of input/output waveforms. This is beneficial for sensitive loads.
5. Conclusion

In this article differences between modular and non-modular solutions for photovoltaic MPPT converters have been described. Initially the main circuit of the individual solution have been shown for selected application. Main focus was given on the performance from cost, volume and efficiency point of view. It was shown, that modular solution enables more design flexibility whereby mentioned parameters can be modified to the target application. Investigation was performed in parametric ways, and individual variables were described in dependency on the operating conditions of presented solutions.

As regards the evaluation of the financial charges for individual system constructions, the modulation rate is not directly increasing investments what was related to the different component selection. The modular cost can be lower compared to non-modular up to a certain count of the modules (up to 16). Due to the high spin rate, the system can be constructed from a small amount of modulation, which reduces the total volume of the system. The modular system provides a smaller dimension to the number of modules 10 compared to a non-modular system but increases the number of individual building blocks in the modular system directly to the overall efficiency of the system.

Next steps in our research will be: design, practical realization of the physical samples and testing of the proposed modular system.

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References